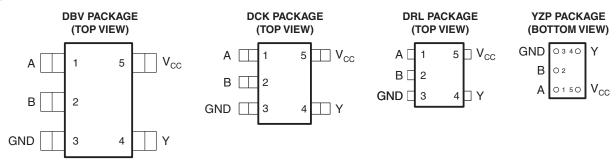


## FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V •
- Max t<sub>nd</sub> of 4 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>cc</sub>
- ±24-mA Output Drive at 3.3 V .
- Ioff Supports Partial-Power-Down Mode

Operation

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

# **DESCRIPTION/ORDERING INFORMATION**

This single 2-input exclusive-OR gate is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The SN74LVC1G86 performs the Boolean function  $Y = A \oplus B$  or  $Y = \overline{AB} + A\overline{B}$  in positive logic.

A common application is as a true/complement element. If the input is low, the other input is reproduced in true form at the output. If the input is high, the signal on the other input is reproduced inverted at the output.

NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G86YZPR	CH_
	SOT (SOT-23) – DBV	Reel of 3000	SN74LVC1G86DBVR	C86
–40°C to 85°C	SOT (SOT-23) - DBV	Reel of 250	SN74LVC1G86DBVT	C00_
		Reel of 3000	SN74LVC1G86DCKR	CU
	SOT (SC-70) – DCK	Reel of 250	SN74LVC1G86DCKT	CH_

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. (2)YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



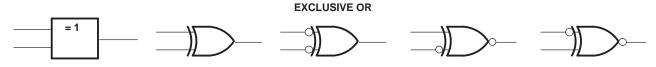
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

#### FUNCTION TABLE

INPL	OUTPUT				
Α	В	Y			
L	L	L			
L	Н	Н			
н	L	н			
н	Н	L			

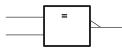
# **EXCLUSIVE-OR LOGIC**

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.



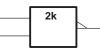
These are five equivalent exclusive-OR symbols valid for an SN74LVC1G86 gate in positive logic; negation may be shown at any two ports.

LOGIC-IDENTITY ELEMENT



The output is active (low) if all inputs stand at the same logic level (i.e., A = B).

#### EVEN-PARITY ELEMENT



The output is active (low) if an even number of inputs (i.e., 0 or 2) are active.

#### **ODD-PARITY ELEMENT**



The output is active (high) if an odd number of inputs (i.e., only 1 of the 2) are active.

# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>	Input voltage range <sup>(2)</sup>			V
Vo	Voltage range applied to any output in the	he high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current V <sub>O</sub> < 0			-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through $V_{CC}$ or GNE	)		±100	mA
		DBV package		206	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCK package		252	°C/W
		YZP package		132	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT	
	Quantu valta na	Operating	1.65	5.5	V	
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		v	
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>			
	High-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		N	
VIH		$V_{CC}$ = 3 V to 3.6 V	2		V	
		$V_{CC}$ = 4.5 V to 5.5 V	$0.7 \times V_{CC}$			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$		
	Low-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7	V	
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	V	
		$V_{CC}$ = 4.5 V to 5.5 V		$0.3 \times V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
		V <sub>CC</sub> = 2.3 V		-8		
I <sub>OH</sub>	High-level output current			-16	mA	
		$V_{CC} = 3 V$		-24		
		V <sub>CC</sub> = 4.5 V		-32		
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8		
I <sub>OL</sub>	Low-level output current	N 2)/		16	mA	
		$V_{CC} = 3 V$		24		
		V <sub>CC</sub> = 4.5 V		32	-	
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20		
$\Delta t / \Delta v$	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		$V_{CC} = 5 V \pm 0.5 V$				
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT
		I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1		
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
V		$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		N/
V <sub>OH</sub>		I <sub>OH</sub> = -16 mA	2.14	2.4		V
		$I_{OH} = -24 \text{ mA}$	- 3 V	2.3		
		I <sub>OH</sub> = -32 mA	4.5 V	3.8		
		I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1	
		I <sub>OL</sub> = 4 mA	1.65 V		0.45	
V		I <sub>OL</sub> = 8 mA	2.3 V		0.3	V
V <sub>OL</sub>		I <sub>OL</sub> = 16 mA	3 V		0.4	v
		I <sub>OL</sub> = 24 mA	3 V		0.55	
		I <sub>OL</sub> = 32 mA	4.5 V		0.55	
I <sub>I</sub>	A or B input	$V_{I} = 5.5 \text{ V or GND}$	0 to 5.5 V		±5	μΑ
I <sub>off</sub>		$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	0		±10	μΑ
I <sub>CC</sub>		$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	1.65 V to 5.5 V		10	μΑ
$\Delta I_{CC}$		One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μΑ
Ci		V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V	6		pF

(1) All typical values are at  $V_{CC} = 3.3$  V,  $T_A = 25^{\circ}C$ .

### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	2.1	9.1	1	4.5	0.6	4	0.8	3.3	ns

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  or 50 pF (unless otherwise noted) (see Figure 2)

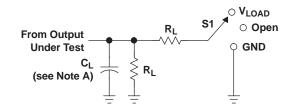
PARAMETER	FROM (INPUT)	TO (OUTPUT)				V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V	
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	3.5	9.9	1.8	5.5	1.3	5	1	4	ns

### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT
	FARAMETER	TEST CONDITIONS	TYP	TYP	TYP	ТҮР	UNIT
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	22	22	22	24	pF

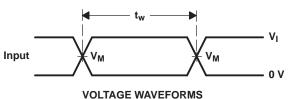
### PARAMETER MEASUREMENT INFORMATION



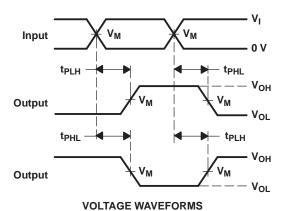
LOAD CIRCUIT

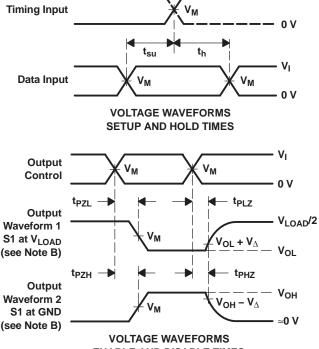
TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INF	PUTS			•	-	N/
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	VM	V <sub>LOAD</sub>	CL	RL	$V_{\Delta}$
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	15 pF	<b>1 Μ</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	15 pF	1 MΩ	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 MΩ	0.3 V
5 V $\pm$ 0.5 V	V <sub>CC</sub>	≤2.5 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	15 pF	1 MΩ	0.3 V



PULSE DURATION





#### ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

NOTES: A.  $C_{\text{L}}$  includes probe and jig capacitance.

**PROPAGATION DELAY TIMES** 

INVERTING AND NONINVERTING OUTPUTS

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z\_O = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

### Figure 1. Load Circuit and Voltage Waveforms

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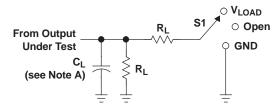
# SN74LVC1G86 SINGLE 2-INPUT EXCLUSIVE-OR GATE



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SCES222N-APRIL 1999-REVISED FEBRUARY 2007

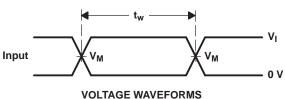
#### PARAMETER MEASUREMENT INFORMATION



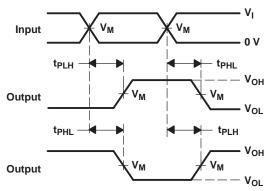
TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LO	AD	CIR	CUI	Г

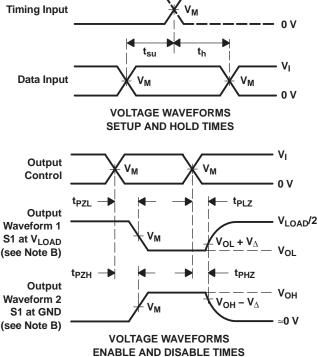
N	INF	PUTS	V	V	•		N
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	VM	V <sub>LOAD</sub>	CL	RL	$V_{\Delta}$
$1.8~V\pm0.15~V$	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>1 k</b> Ω	0.15 V
$\textbf{2.5 V} \pm \textbf{0.2 V}$	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>500</b> Ω	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V
5 V $\pm$ 0.5 V	V <sub>CC</sub>	≤2.5 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	50 pF	<b>500</b> Ω	0.3 V



PULSE DURATION







#### ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

- NOTES: A.  $C_{\text{L}}$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z\_O = 50  $\Omega$
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

### Figure 2. Load Circuit and Voltage Waveforms

VE IEXAS INSTRUMENTS www.ti.com

22-Oct-2007

## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finisł	n MSL Peak Temp <sup>(3)</sup>
SN74LVC1G86DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G86YZPR	ACTIVE	WCSP	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

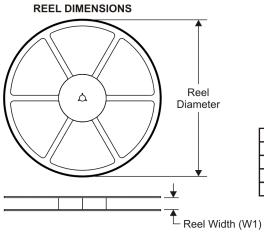
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

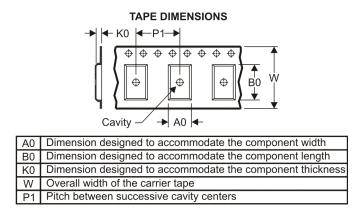


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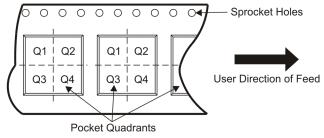
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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G86DBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G86DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G86DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G86DBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G86DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G86DCKT	SC70	DCK	5	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74LVC1G86DRLR	SOT	DRL	5	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3



# PACKAGE MATERIALS INFORMATION

31-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G86DBVR	SOT-23	DBV	5	3000	205.0	200.0	33.0
SN74LVC1G86DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G86DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G86DBVT	SOT-23	DBV	5	250	205.0	200.0	33.0
SN74LVC1G86DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74LVC1G86DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74LVC1G86DRLR	SOT	DRL	5	4000	202.0	201.0	28.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

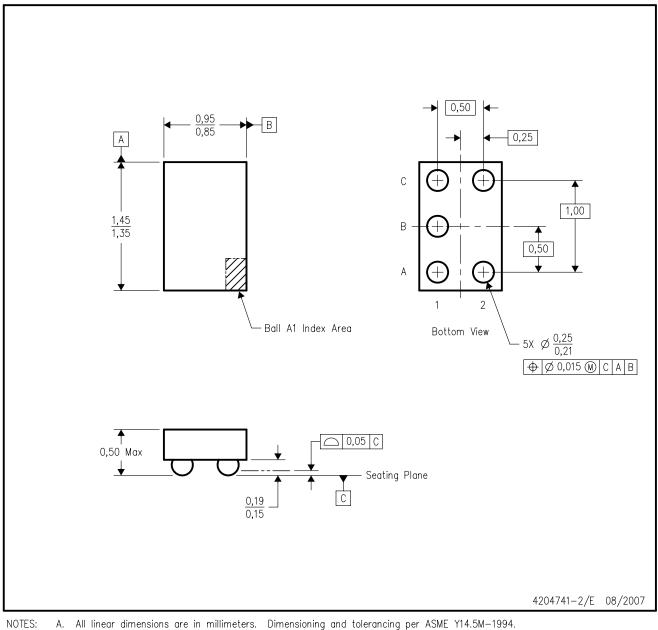
🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

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